



# NCE N-Channel Enhancement Mode Power MOSFET

### Description

The NCE0140IA uses advanced trench technology and design to provide excellent  $R_{DS(ON)}$  with low gate charge. It can be used in a wide variety of applications.

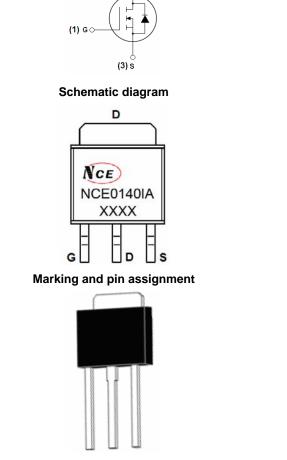
#### **General Features**

- $V_{DS} = 100V, I_D = 40A$   $R_{DS(ON)} < 17m\Omega @ V_{GS} = 10V$  (Typ:12m $\Omega$ )  $R_{DS(ON)} < 18m\Omega @ V_{GS} = 4.5V$  (Typ:13m $\Omega$ )
- Special process technology for high ESD capability
- High density cell design for ultra low Rdson
- Fully characterized avalanche voltage and current
- Good stability and uniformity with high E<sub>AS</sub>
- Excellent package for good heat dissipation

#### Application

- Power switching application
- Hard switched and high frequency circuits
- Uninterruptible power supply

100% UIS TESTED! 100% ΔVds TESTED!



(2) D

#### TO-251 top view

#### **Package Marking and Ordering Information**

Device Marking	Device	Device Package	Reel Size	Tape width	Quantity
NCE0140IA	NCE0140IA	TO-251	-	-	-

#### Absolute Maximum Ratings (T<sub>c</sub>=25℃ unless otherwise noted)

Parameter	Symbol	Limit	Unit	
Drain-Source Voltage	Vds	100	V	
Gate-Source Voltage	Vgs	±20	V	
Drain Current-Continuous	Ι <sub>D</sub>	40	А	
Drain Current-Continuous(Tc=100℃)	I <sub>D</sub> (100℃)	28	А	
Pulsed Drain Current	I <sub>DM</sub>	160	А	
Maximum Power Dissipation	PD	140	W	
Derating factor	-	0.93	W/℃	
Single pulse avalanche energy (Note 5)	E <sub>AS</sub>	400	mJ	
Operating Junction and Storage Temperature Range	T <sub>J</sub> ,T <sub>STG</sub>	-55 To 175	°C	





NCE0140IA

#### **Thermal Characteristic**

Thermal Resistance, Junction-to-Case <sup>(Note 2)</sup> R <sub>0JC</sub> 1.07 °C/W
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#### **Electrical Characteristics (Tc=25**<sup>°</sup>C unless otherwise noted)

Parameter	Symbol	Condition	Min	Тур	Max	Unit	
Off Characteristics							
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	V <sub>GS</sub> =0V I <sub>D</sub> =250µA	100	110	-	V	
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	V <sub>DS</sub> =100V,V <sub>GS</sub> =0V	-	-	1	μA	
Gate-Body Leakage Current	I <sub>GSS</sub>	V <sub>GS</sub> =±20V,V <sub>DS</sub> =0V	-	-	±100	nA	
On Characteristics (Note 3)			•				
Gate Threshold Voltage	V <sub>GS(th)</sub>	V <sub>DS</sub> =V <sub>GS</sub> ,I <sub>D</sub> =250µA	0.9	1.1	1.5	V	
Drain Course On State Desistance		V <sub>GS</sub> =10V, I <sub>D</sub> =20A	-	12	17		
Drain-Source On-State Resistance	R <sub>DS(ON)</sub>	V <sub>GS</sub> =4.5V, I <sub>D</sub> =20A	- 13 18		18	mΩ	
Forward Transconductance	<b>g</b> fs	V <sub>DS</sub> =5V,I <sub>D</sub> =20A	32	-	-	S	
Dynamic Characteristics (Note4)							
Input Capacitance	C <sub>lss</sub>		-	3400	-	PF	
Output Capacitance	C <sub>oss</sub>	V <sub>DS</sub> =30V,V <sub>GS</sub> =0V, F=1.0MHz	-	290	-	PF	
Reverse Transfer Capacitance	C <sub>rss</sub>		-	221	-	PF	
Switching Characteristics (Note 4)							
Turn-on Delay Time	t <sub>d(on)</sub>		-	15	-	nS	
Turn-on Rise Time	tr	V <sub>DD</sub> =30V,I <sub>D</sub> =2A,R <sub>L</sub> =15Ω,	-	11	-	nS	
Turn-Off Delay Time	t <sub>d(off)</sub>	R <sub>G</sub> =2.5Ω,V <sub>GS</sub> =10V	-	52	-	nS	
Turn-Off Fall Time	t <sub>f</sub>		-	13	-	nS	
Total Gate Charge	Qg		-	94	-	nC	
Gate-Source Charge	Q <sub>gs</sub>	I <sub>D</sub> =20A,V <sub>DD</sub> =50V,V <sub>GS</sub> =10V	-	16	-	nC	
Gate-Drain Charge	Q <sub>gd</sub>		-	24	-	nC	
Drain-Source Diode Characteristics							
Diode Forward Voltage (Note 3)	V <sub>SD</sub>	V <sub>GS</sub> =0V,I <sub>S</sub> =20A	-	0.85	1.2	V	
Diode Forward Current (Note 2)	I <sub>S</sub>		-	-	40	Α	
Reverse Recovery Time	trr	T <sub>J</sub> = 25°C, I <sub>F</sub> = 20A	-	33		nS	
Reverse Recovery Charge	Qrr	di/dt = 100A/µs <sup>(Note3)</sup>	-	54		nC	
Forward Turn-On Time	t <sub>on</sub>	Intrinsic turn-on time is negligible (turn-on is dominated by LS+LD)				y LS+LD)	

#### Notes:

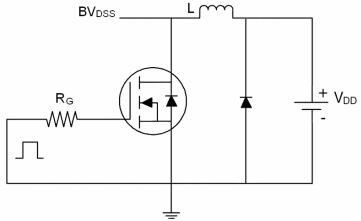
- 1. Repetitive Rating: Pulse width limited by maximum junction temperature.
- **2.** Surface Mounted on FR4 Board,  $t \le 10$  sec.
- **3.** Pulse Test: Pulse Width  $\leq$  300µs, Duty Cycle  $\leq$  2%.
- 4. Guaranteed by design, not subject to production
- 5. EAS condition: Tj=25 $^\circ \! \mathbb{C}$  ,V\_{DD}=50V,V\_G=10V,L=0.5mH,Rg=25\Omega



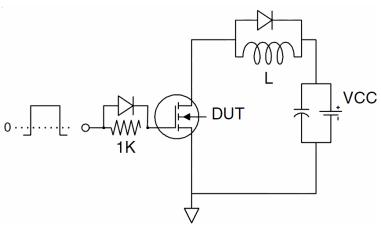
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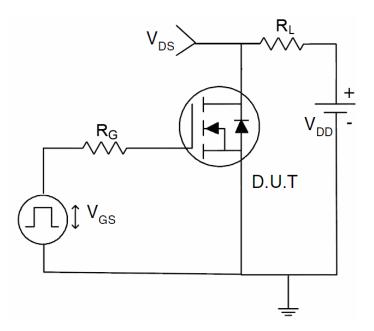
### Test Circuit 1) E<sub>AS</sub> test Circuit



### 2) Gate charge test Circuit



3) Switch Time Test Circuit



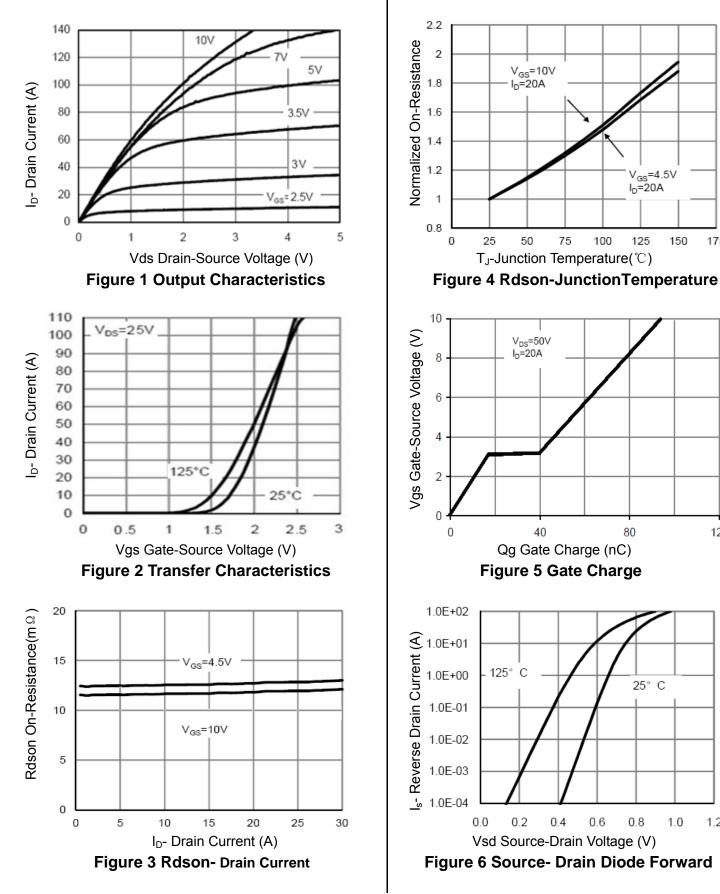




175

120

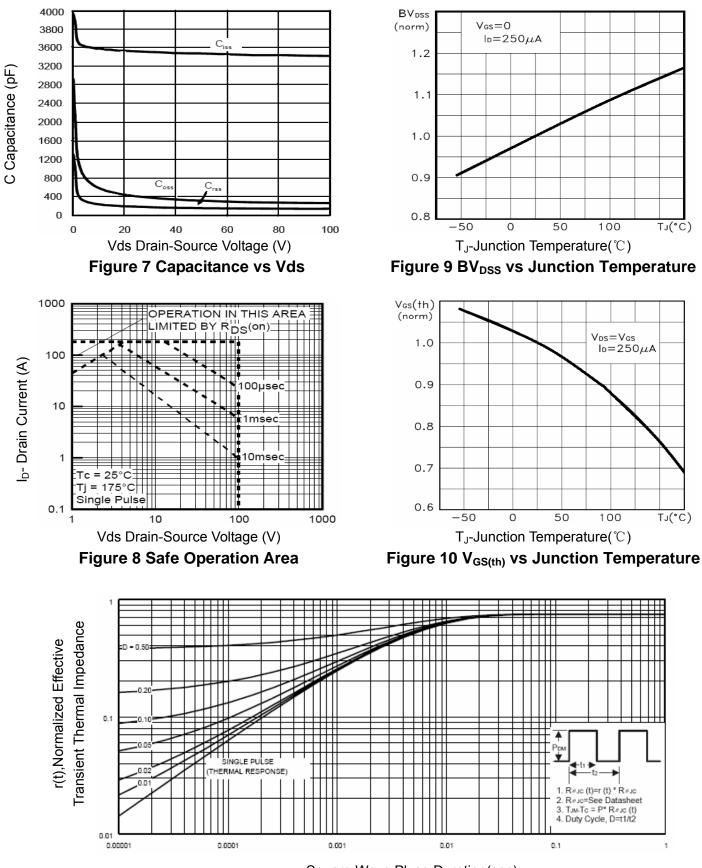
## **Typical Electrical and Thermal Characteristics (Curves)**

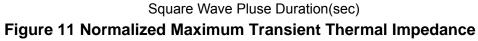


1.2







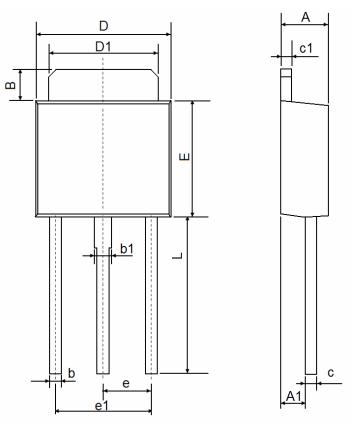




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# **TO-251 Package Information**



Symbol	Dimensions	s In Millimeters	Dimensions In Inches		
	Min.	Max.	Min.	Max.	
A	2.200	2.400	0.087	0.094	
A1	1.050	1.350	0.042	0.054	
В	1.350	1.650	0.053	0.065	
b	0.500	0.700	0.020	0.028	
b1	0.700	0.900	0.028	0.035	
С	0.430	0.580	0.017	0.023	
c1	0.430	0.580	0.017	0.023	
D	6.350	6.650	0.250	0.262	
D1	5.200	5.400	0.205	0.213	
E	5.400	5.700	0.213	0.224	
е	2.300 TYP		0.091 TYP		
e1	4.500	4.700	0.177	0.185	
L	7.500	7.900	0.295	0.311	





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